

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

**Claim 1.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted on a principle side of said wiring substrate and electrically connected to said wiring via at least one bump, the entire said principle side having of said wiring substrate being a common planar surface over its entirety;

an external connection terminal electrically connected to said wiring, said external connection terminal arranged on a same side of said wiring substrate to which said semiconductor device is mounted; and

an insulating resin layer, said insulating resin layer having a thickness greater than said semiconductor device, provided between said wiring substrate and said external connection terminal and functioning to relax stress between said semiconductor module and a board to which the semiconductor module is mounted.

**Claim 2.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted on a principle side of said wiring substrate and electrically connected to said wiring via at least one bump, the entire said principle side having of said wiring substrate being a

~~common planar surface over its entirety;~~

an external connection terminal electrically connected to said wiring,  
said external connection terminal arranged on a same side of said wiring  
substrate to which said semiconductor device is mounted; and

an insulating resin layer formed on the same side of said wiring  
substrate to which said semiconductor device is mounted,

wherein said insulating resin layer has an inclined portion and a flat  
portion on which said external connection terminal is arranged, said insulating  
resin layer functioning to relax stress between said semiconductor module and a  
board to which said semiconductor module is mounted, and

wherein a part of said wiring electrically connected between a  
terminal on said semiconductor device and said external connection terminal is  
formed on said inclined portion of said insulating resin layer.

**Claim 3.** (Previously Presented) A semiconductor module according to claim 1 or  
claim 2, wherein said insulating resin layer has a shape defined by a printed  
pattern.

**Claim 4.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted on a principle side of  
said wiring substrate and electrically connected to said wiring via at least one  
bump, the entire said principle side having of said wiring substrate being a  
common planar surface over its entirety;

an insulating resin layer having a function of relaxing stress between

said semiconductor module and a board to which said semiconductor module is mounted; and

an external connection terminal on said insulating resin layer and electrically connected to said wiring,

wherein said insulating resin layer is one of a plurality of said insulating resin layers that are collectively formed, with shapes defined by printed patterns of insulating material, on a same side of said wiring substrate to which said semiconductor device is mounted, said wiring substrate representing one component wiring substrate formed on a wafer board comprising a plurality of said wiring substrates.

**Claim 5.** (Previously Presented) A semiconductor module according to claim 1 or claim 2, wherein said insulating resin layer substantially encloses said semiconductor device.

**Claim 6.** (Original) A semiconductor module according to claim 5, wherein said insulating resin layer is frame-shaped.

**Claim 7.** (Previously Presented) A semiconductor module according to claim 5, wherein an inclination of an inner circumferential side is relatively gradual to that of an outer circumferential side of said insulating resin layer.

**Claim 8.** (Original) A semiconductor module according to claim 1, wherein a plurality of insulating resin layers are used instead of said insulating resin layer and arranged as if they enclose said semiconductor device.

**Claim 9.** (Original) A semiconductor module according to claim 1, wherein said wiring substrate is a silicon substrate or a glass substrate.

**Claim 10.** (Previously Presented) A semiconductor module according to claim 1, wherein said insulating resin layer is made of insulating material having an elastic modulus from within the range of approx. 0.1Gpa to approx. 10Gpa.

**Claim 11.** (Original) A semiconductor module according to claim 1, wherein a film thickness of said insulating resin layer is approx. 10 $\mu$ m to approx. 350 $\mu$ m.

**Claim 12.** (Currently Amended) A semiconductor module according to claim 1, wherein said semiconductor device is one of a semiconductor chip, a chip scale package (CSP), a ball grid array (BGA), and ~~an~~ a wafer-level CSP.

**Claim 13.** (Original) A semiconductor module according to claim 1, wherein a sum of a thickness of said insulating resin layer and a height of said external connection terminal is greater than a distance from the mounted surface of said semiconductor device to a rear surface thereof.

**Claim 14.** (Previously Presented) A semiconductor module according to claim 1, wherein a sum of a thickness of said insulating resin layer and a height of said external connection terminal is substantially equal to a distance from the mounted surface of said semiconductor device to the rear surface thereof.

**Claim 15.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted on and electrically connected to said wiring on a principle side of said wiring substrate via ~~a~~ at least one bump of said semiconductor device, the entire said principle side ~~having of~~ said wiring substrate being a common planar surface over its entirety;

an external connection terminal electrically connected to said wiring, said external connection terminal arranged on a same side of said wiring substrate to which said semiconductor device is mounted; and

an insulating resin layer formed on the same side of said wiring substrate on which said semiconductor device is mounted,

wherein said insulating resin layer has a function of relaxing stress between said semiconductor module and a board to which said semiconductor module is mounted, and

wherein said wiring substrate is a silicon substrate.

**Claim 16.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted and electrically connected to the wiring on a principle side of said wiring substrate via ~~a~~ at least one bump of said semiconductor device, the entire said principle side of said wiring substrate being ~~having~~ a common planar surface over its entirety;

an external connection terminal electrically connected to said wiring, said external connection terminal arranged on a same side of said wiring substrate to which said semiconductor device is mounted; and

wherein said semiconductor device has an insulating resin layer having a function of relaxing stress between said semiconductor device and said wiring substrate to which said semiconductor device is mounted, said semiconductor device being mounted on said wiring substrate without using an underfill.

**Claim 17.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted and electrically connected to the wiring on a principle side of said wiring substrate via a ~~at least one~~ bump of said semiconductor device, ~~the entire said principle side having of said wiring substrate being a common planar surface over its entirety;~~

an external connection terminal electrically connected to said wiring, said external connection terminal arranged on a same side of said wiring substrate to which said semiconductor device is mounted;

a first insulating resin layer formed on the same side of said wiring substrate to which said semiconductor device is mounted, said first insulating resin layer having a function of relaxing stress between said semiconductor module and a board to which said semiconductor module is mounted; and

wherein said semiconductor device has a second insulating resin layer having a function of relaxing the stress between said semiconductor device and said wiring substrate to which said semiconductor device is mounted, said semiconductor device being mounted on said wiring substrate without using an underfill.

**Claim 18.** (Previously Presented) A semiconductor module according to claim 16, wherein said insulating resin layer is made of an insulating material having an elastic modulus from within the range of approx. 0.1Gpa to approx. 10Gpa.

**Claim 19.** (Original) A semiconductor module according to claim 16, wherein a film thickness of said insulating resin layer is approx. 10 $\mu$ m to approx. 350 $\mu$ m.

**Claim 20.** (Currently Amended) A semiconductor module according to claim 16, wherein said insulating resin layer has a shape defined by a printed pattern.

**Claim 21.** (Previously Presented) A semiconductor module according to claim 16, wherein said external connection terminal is formed on a second insulating resin layer, which is formed on said semiconductor device mounted side of said wiring substrate, having an inclined portion at a given inclination to the mounting surface and a substantially plane flat portion on which said external connection terminal is arranged.

**Claim 22.** (Withdrawn) A mounting structure, comprising:

a wiring substrate on which wiring is formed;

a semiconductor device electrically connected to the wiring formed on said wiring substrate through bumps; and

encapsulant for filling a gap between said wiring substrate and said semiconductor device,

wherein the encapsulant comprises a material not including a filler.

**Claim 23.** (Previously Presented) A mounting structure comprising a semiconductor module, a heat conductive material and an external substrate to which said semiconductor module is mounted,

wherein said semiconductor module includes:

a wiring substrate on which wiring is formed;

a semiconductor device mounted on a principle side of said wiring substrate and electrically connected to said wiring, said principle side having a planar surface over its entirety;

an external connection terminal electrically connected to said wiring, said external connection terminal arranged on a same side of said wiring substrate to which said semiconductor device is mounted; and

an insulating resin layer, said insulating resin layer having a thickness greater than said semiconductor device, provided between said wiring substrate and said external connection terminal and functioning to relax stress between said semiconductor module and said external substrate to which the semiconductor module is mounted, and

wherein said heat conductive material layer is formed on said external substrate to which said semiconductor module is mounted and said semiconductor device of said semiconductor module is connected to said heat conductive material layer.

**Claim 24.** (Previously Presented) A semiconductor module according to claim 1, further comprising a metal member connecting said semiconductor device to a circuit board.



**Claim 25.** (Currently Amended) A semiconductor module ~~according to claim 4,~~  
comprising:

a wiring substrate on which wiring is formed;

a semiconductor device mounted on a principle side of said wiring  
substrate and electrically connected to said wiring, the entire said principle side of  
said wiring substrate being a common planar surface;

an external connection terminal electrically connected to said wiring,  
said external connection terminal arranged on a same side of said wiring  
substrate to which said semiconductor device is mounted; and

an insulating resin layer, said insulating resin layer having a  
thickness greater than said semiconductor device, provided between said wiring  
substrate and said external connection terminal and functioning to relax stress  
between said semiconductor module and a board to which the semiconductor  
module is mounted,

wherein said semiconductor device is connected to said wiring  
substrate by die-attaching and said semiconductor device is electrically connected  
to the wiring formed on said wiring substrate by wire bonding.

**Claim 26.** (Currently Amended) A semiconductor module, comprises:

a wiring substrate on which wiring is formed;

a semiconductor device being both mounted on a principle side of  
said wiring substrate and electrically connected to the wiring formed on said wiring  
substrate via at least one bump of said semiconductor device, the entire said  
principle side having of said wiring substrate being a common planar surface over

~~its entirety;~~

an insulating material covering said semiconductor device; and  
a wiring with an external electrode connected thereto for enabling  
electrical connection of the module to an outer circuit,  
wherein said wiring and said external electrode connected thereto  
are disposed on said insulating material.

**Claim 27.** (Previously Presented) A semiconductor module according to claim 26,  
wherein there is provided an intermediate plate in said insulating material between  
said semiconductor device and said external terminal.

**Claims 28 and 29.** (Canceled)

**Claim 30.** (Currently Amended) A semiconductor module, comprising:

a wiring substrate on which wiring is formed;  
a semiconductor device being both mounted on a principle side of  
said wiring substrate and electrically connected to said wiring via at least one  
bump of said semiconductor device, the entire said principle side having of said  
wiring substrate being a common planar surface over its entirety;  
an insulating resin layer having a function of relaxing stress between  
said semiconductor module and a board to which said semiconductor module is  
mounted; and  
an external connection terminal on said insulating resin layer and  
electrically connected via said wiring to a terminal of said semiconductor device,  
wherein said insulating resin layer is one of a plurality of such

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insulating resin layers that are collectively molded on a wafer board comprising a plurality of said wiring substrates, each said insulating resin layer has a thickness greater than said semiconductor device between said wiring substrate and said external connection terminal.

**Claim 31.** (Previously Presented) A semiconductor module according to claim 30, wherein each said insulating resin layer is formed on an outer peripheral portion of a separate said wiring substrate.